Data Sheet

RTC6608OSP

0.03 GHz - 6.0 GHz SPDT Switch







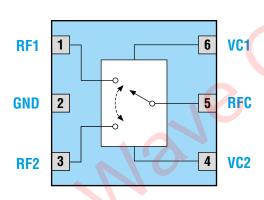


MAY 2021 - Ver. 1.9

Description

The RTC66080SP is a SPDT antenna switch designed for frequency range from 0.03 GHz up to 6.0 GHz range. The RTC66080SP is processed in advanced CMOS SOI (silicon-on-insulator) technology featuring low insertion loss, high isolation and sustain high linearity at low supply voltage. The excellent performance of RTC66080SP make it ideal to be applied in wireless applications for WLAN, Bluetooth® and IEEE 802.11a/b/g/n/ac transmit/receive function. The RTC66080SP is housed in a compact 6L QFN1.0mm x 1.0mm plastic package.

Functional Block Diagram



Features

Frequency Range : 0.03 – 6.0 GHz

Low Control Voltage : 1.6 ~ 3.6 V

Low Insertion Loss

High Isolation

High P1dB

 Small and Low Profile Package : 6L QFN 1.0mm x 1.0mm x 0.4mm (max)

RoHS Compliant, Pb-free, Halogen Free

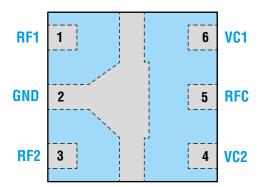
Moisture Sensitivity Level : MSL 1

Applications

IEEE 802.11a/b/g/n/ac WLAN Networks

Mobile Devices

Pin Assignments



Top View Through Package

Pin No.	Pin Name	Description
1	RF1	RF Signal 1. DC blocking capacitor is needed
2	GND	Ground
3	RF2	RF Signal 2. DC blocking capacitor is needed
4	VC2	DC control voltage 2
5	RFC	Antenna port. DC blocking capacitor is needed
6	VC1	DC control voltage 1
Expos	ed Paddle	It must be connected to a ground through PCB via for best performance

Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit
Control Voltage	VC1, VC2	+5	V
Input power	P _{IN}	+33	dBm
Operating Ambient Temperature	T _A	-40 ~ +105	°C
Storage Temperature	T _{STG}	-40 ~ +150	°C

NOTE: Stresses above those conditions listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only. Functional operation of the device above those conditions indicated in the Absolute Maximum Ratings is not implied. The functional operation of the device at the conditions in between Recommended Operating Ranges and Absolute Maximum Ratings for extended periods may affect device reliability.

Recommended Operating Ranges

Parameter	Symbol	Min	Тур	Max	Unit
Operating Frequency	f	0.03		6.0	GHz
Control Voltage High	VC1(H), VC2(H)	1.6	3.3 or 1.8	3.6	V
Control Voltage Low	VC1(L), VC2(L)	0	0	0.4	V

NOTE: Recommended Operating Ranges indicate conditions for which the device is intended to be functional, but does not guarantee specific performance limits.

Truth Table

Low Insertion Loss Path	VC1	VC2
RFC – RF1	0	1
RFC – RF2	1	0

NOTE: "1" = $1.6 \sim 3.6 \text{ V}$, "0" = $0 \sim 0.4 \text{ V}$

Electrical Specifications (I)

 $T_A = +25^{\circ}C$, 50Ω system with control voltage VC = 0/3.3 V, $P_{IN} = 0$ dBm, unless otherwise noted

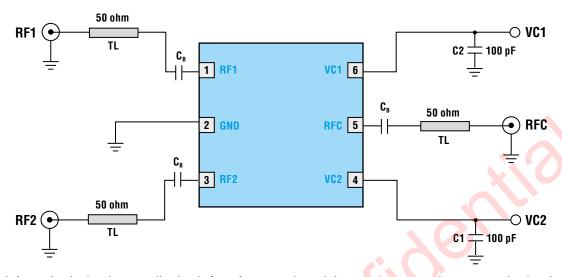
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
	IL_1	30 – 100 MHz		0.32	0.55	dB
Insertion Loss	IL_2	100 – 1000 MHz		0.39	0.60	dB
IIISEITIOII LOSS	IL_3	2.4 – 2.5 GHz		0.40	0.60	dB
	IL_4	4.9 – 6.0 GHz		0.75	0.95	dB
	lso_1	30 – 100 MHz	41	46	1.17	dB
Isolation	lso_2	100 – 1000 MHz	23	28		dB
(RF1,2 to RFC)	lso_3	2.4 – 2.5 GHz	22	25		dB
	Iso_4	4.9 – 6.0 GHz	23	27		dB
	Iso_5	30 – 100 MHz	41	46		dB
Isolation	Iso_6	100 – 1000 MHz	24	28		dB
(RF1 to RF2)		2.4 – 2.5 GHz	22	25		dB
	s	4.9 – 6.0 GHz	27	31		dB
	RL_1	30 – 100 MHz	20	32		dB
Return Loss	RL_2	100 – 1000 MHz	20	26		dB
(Insertion Loss State)	RL_3	2.4 – 2.5 GHz	18	23		dB
	RL_4	4.9 – 6.0 GHz	14	19		dB
Input Power for 1dB	P1dB_1	@ 2.4 GHz	30	33		dBm
Compression	P1dB_2	@ 5.8 GHz	29	32		dBm
Input 3rd Order Distortion Intercept Point	IIP3	PIN = +20 dBm/tone Δf = 1 MHz, 2.45 GHz VC = 2.7 V	42	44		dBm
2nd Harmonic	2fo_1-1	f = 2.45 GHz	70	73		dBc
3rd Harmonic	3fo_2-1	Pin = +25 dBm, CW	70	76		dBc
2nd Harmonic	2fo_1-2	f = 5.8 GHz	71	74		dBc
3rd Harmonic	3fo_2-2	Pin = +24 dBm, CW	77	82		dBc
Linear Power for EVM	EVM_2G	f = 2.45 GHz, WLAN,802.11g,0FDM, 54Mbps, 64QAM, Pin for 2.5% error		27		dBm
Switching Rise/Fall Time	tr	10/90% to 90/10% RF		85	130	ns
Switching On/Off Time	tc	50% Vc to 90/10% RF 115 14		140	ns	
Control Current	lctl	VC = 3.3 V		5	15	μΑ

Electrical Specifications (II)

 $T_A = +25^{\circ}C$, 50Ω system with control voltage VC = 0/1.8 V, $P_{IN} = 0$ dBm, unless otherwise noted

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
	IL_1	30 – 100 MHz		0.37	0.60	dB
Incortion I acc	IL_2	100 – 1000 MHz		0.43	0.65	dB
Insertion Loss	IL_3	2.4 – 2.5 GHz		0.57	0.80	dB
	IL_4	4.9 – 6.0 GHz		0.80	1.05	dB
	Iso_1	30 – 100 MHz	41	46		dB
Isolation	Iso_2 100 – 1000 MHz		24	28		dB
(RF1,2 to RFC)	Iso_3	2.4 – 2.5 GHz	20	23		dB
	Iso_4	4.9 – 6.0 GHz	23	27	>	dB
	Iso_5	30 – 100 MHz	41	46		dB
Isolation	lso_6	100 – 1000 MHz	25	30		dB
(RF1 to RF2)	Iso7	2.4 – 2.5 GHz	20	24		dB
	Iso_8	4.9 – 6.0 GHz	26	30		dB
	RL_1	30 – 100 MHz	25	32		dB
Return Loss	RL_2	100 – 1000 MHz	20	26		dB
(Insertion Loss State)	RL_3	2.4 – 2.5 GHz	20	23		dB
	RL_4	4.9 – 6.0 GHz	15	20		dB
Input Power for 1dB	P1dB_1	@ 2.4 GHz 28		31		dBm
Compression	P1dB_2	@ 5.8 GHz	27	30		dBm
Input 3rd Order Distortion Intercept Point	IIP3	PIN = +20 dBm/tone Δf = 1 MHz, 2.45 GHz VC = 1.8 V	39	41		dBm
2nd Harmonic	2fo_1-1	f = 2.45 GHz	64	69		dBc
3rd Harmonic	3fo_2-1	Pin = +25 dBm, CW	56	62		dBc
2nd Harmonic	2fo_1-2	f = 5.8 GHz	63	68		dBc
3rd Harmonic	3fo_2-2	Pin = +24 dBm, CW	53	60		dBc
Linear Power for EVM	EVM_2G	f = 2.45 GHz, WLAN,802.11g,0FDM, 54Mbps, 64QAM, Pin for 2.5% error		24		dBm
Switching Rise/Fall Time	tr	10/90% to 90/10% RF		200	300	ns
Switching On/Off Time	tc	50% Vc to 90/10% RF 140 2		250	ns	
Control Current	lctl	VC = 1.8 V		2	10	μΑ

Application Circuits



NOTE: Information in the above application is for reference only, and does not guarantee the mass production design of the device.

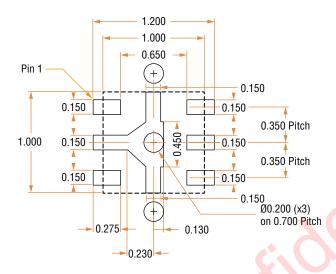
Evaluation Board Bill of Material

Component	Value	Description	Supplier	Part Number
IC		RTC66080SP	RichWave	
C_{B}	68 pF	DC blocking capacitor	Walsin	0402N680J500LT
C1, C2	100 pF	De-coupling capacitor	Walsin	0402N101J500LT

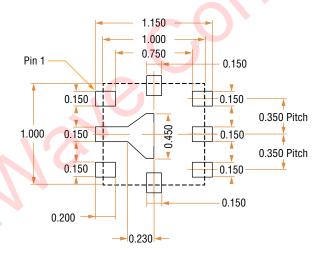
NOTE:

- 1. $C_B = 68$ pF for operation 0.1 ~ 6.0 GHz are required on all RF ports.
- 2. Larger Capacitance recommended for lower frequency operation.
- 3. Exposed paddle in the bottom must be grounded.

Recommended Footprint Patterns



PCB Board Metal & Via Pattern (Top View)

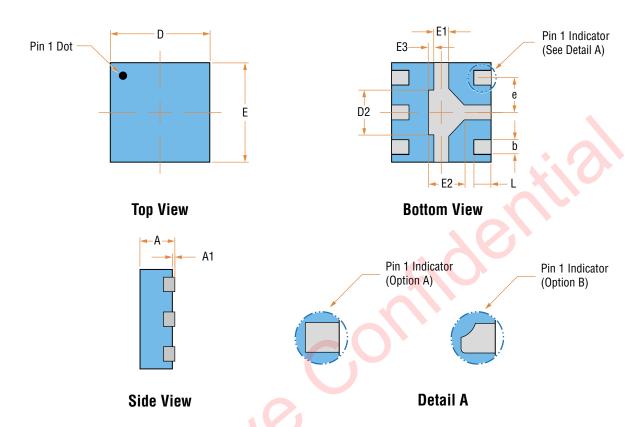


PCB Stencil Pattern (Top View)

NOTE:

- 1. All dimensions are measured in millimeters.
- 2. Drawing is not to scale.

Package Dimensions



6L QFN 1 X 1 X 0.4 - B						
SYMBOL	MIN	ТҮР	MAX			
А	0.300	0.375	0.400			
A1	0.000	0.020	0.050			
b	0.100	0.150	0.200			
D	0.900	1.000	1.100			
D2	0.350	0.450	0.550			
е	0.350 BSC					
E	0.900	1.000	1.100			
E1	0.050	0.150	0.250			
E2	0.310	0.365	0.410			
E3	0.005	0.055	0.105			
L	0.125	0.175	0.225			

NOTE:

- 1. All dimensions are measured in millimeters.
- 2. Drawing is not to scale.
- 3. The shape of the Pin 1 Indicator can be either Option A or Option B, but it must be located within the zone indicated..



Customer Service

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